

Features

- AEC-Q101 Qualified
- Trench LV MOSFET Technology
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device^(Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

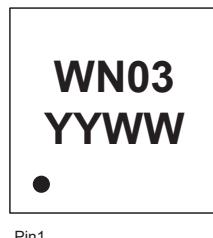
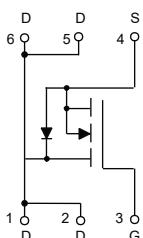
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 80°C/W Junction to Ambient^(Note2)
- Thermal Resistance: 4°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage ^(Note 3)	V_{GS}	+20/-16V	V
Continuous Drain Current	I_D	45	A
$T_C=100^\circ\text{C}$		28	
Pulsed Drain Current ^(Note 4)	I_{DM}	180	A
Total Power Dissipation ^(Note 5)	P_D	31	W

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$.
3. $VGS=+20\text{V}/-16\text{V}$ according AEC-Q101 at $T_j=150^\circ\text{C}$
4. Repetitive rating; pulse width limited by max. junction temperature.
5. P_D is based on max. junction temperature, using junction-case thermal resistance.

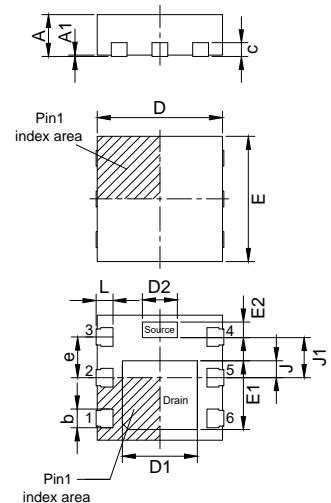
Internal Structure and Marking Code



YYWW: 4 codes in total
YY is the year
WW is the week

N-CHANNEL MOSFET

DFN2020-6(SWF)



DIM	INCH		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.019	0.034	0.50	0.85	
A1	0.000	0.004	0.00	0.10	
c	0.008		0.20		TYP
D	0.074	0.083	1.90	2.10	
E	0.074	0.083	1.90	2.10	
D1	0.043	0.052	1.10	1.30	
E1	0.039	0.048	1.00	1.20	
D2	0.018	0.026	0.46	0.66	
E2	0.005	0.014	0.15	0.35	
J	0.011		0.27		TYP
J1	0.025		0.64		TYP
b	0.007	0.016	0.20	0.40	
e	0.026		0.65		TYP
L	0.005	0.014	0.15	0.35	

N-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	30			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.6	2.2	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=9A$		6.8	9.1	mΩ
		$V_{GS}=4.5V, I_D=8A$		10.2	15	
Gate Resistance	R_g	f=1MHz, Open Drain		2.7		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				45	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=2A$			1.2	V
Reverse Recovery Time	t_{rr}	$I_S=2A, dI_F/dt=100A/\mu s$		19.7		ns
Reverse Recovery Charge	Q_{rr}			9.3		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V, f=1MHz$		1054		pF
Output Capacitance	C_{oss}			175		
Reverse Transfer Capacitance	C_{rss}			152		
Total Gate Charge	Q_g	$V_{DS}=15V, V_{GS}=10V, I_D=9A$		22		nC
Gate-Source Charge	Q_{gs}			3		
Gate-Drain Charge	Q_{gd}			6		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=15V, I_D=9A, R_G=3\Omega$		7.8		ns
Turn-On Rise Time	t_r			11.7		
Turn-Off Delay Time	$t_{d(off)}$			25.4		
Turn-Off Fall Time	t_f			8.1		

Curve Characteristics

Fig.1 - Typical Output Characteristics

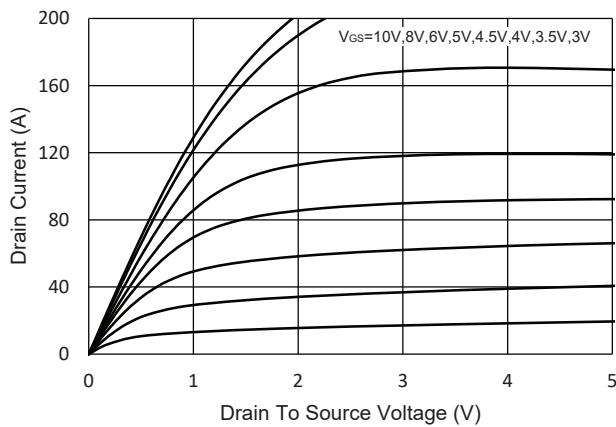


Fig.2 - Transfer Characteristics

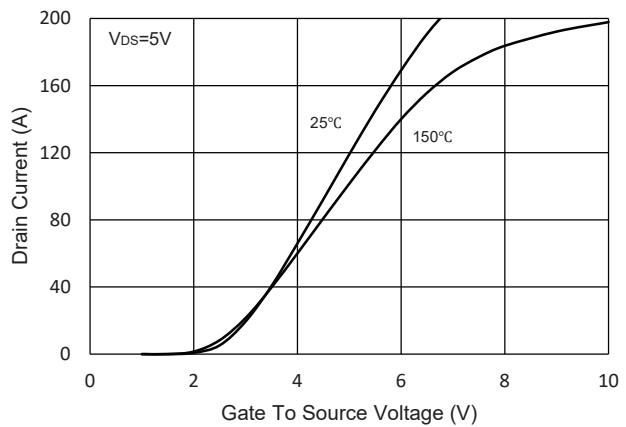


Fig. 3 - $R_{DS(ON)}$ - V_{GS}

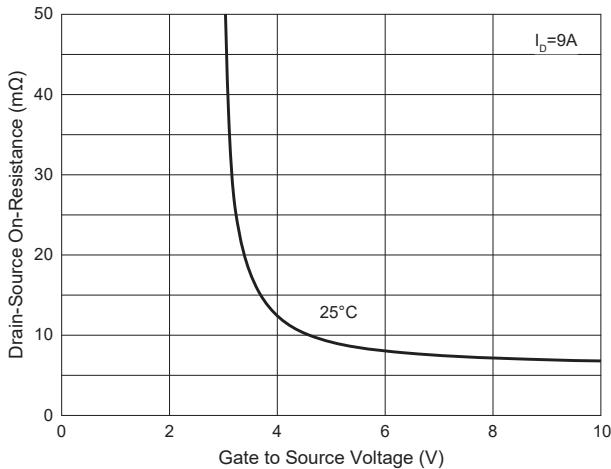


Fig. 4 - $R_{DS(ON)}$ - I_D

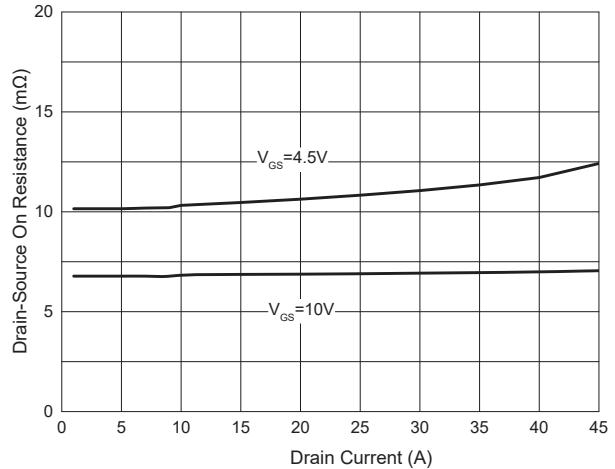


Fig.5 - Capacitance Characteristics

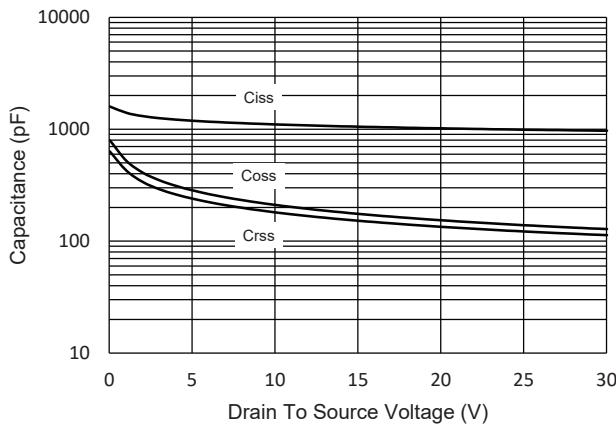
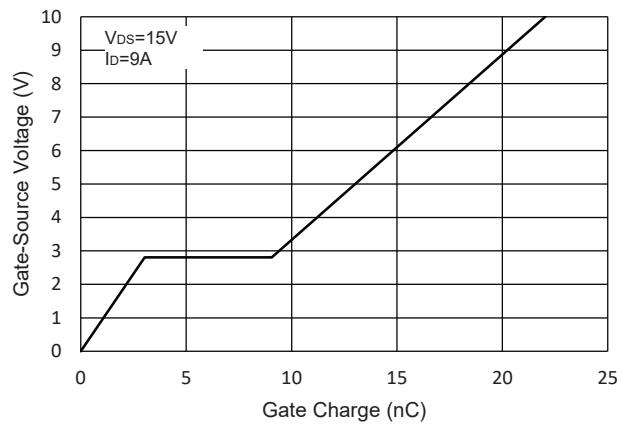


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

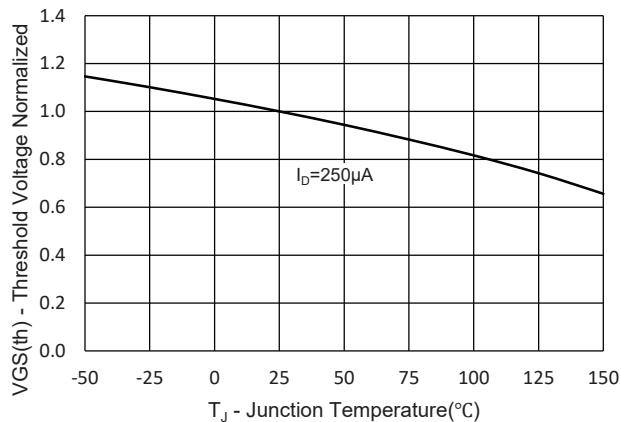


Fig.8 - Normalized On Resistance Characteristics

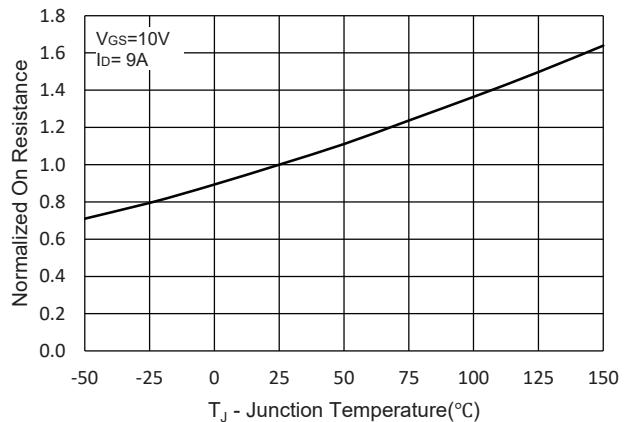


Fig.9 - I_S - V_{SD}

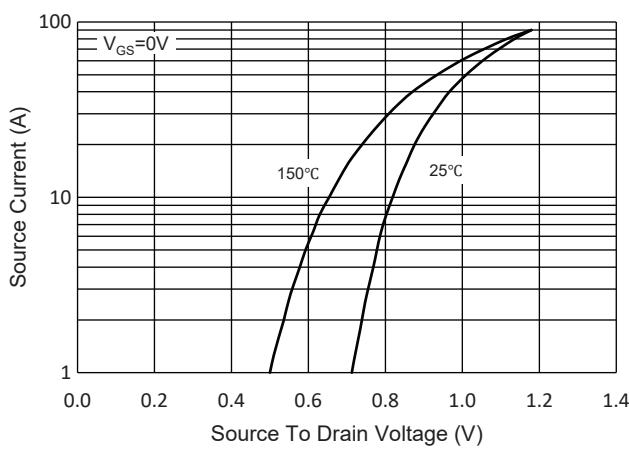


Fig. 10 - Drain Current

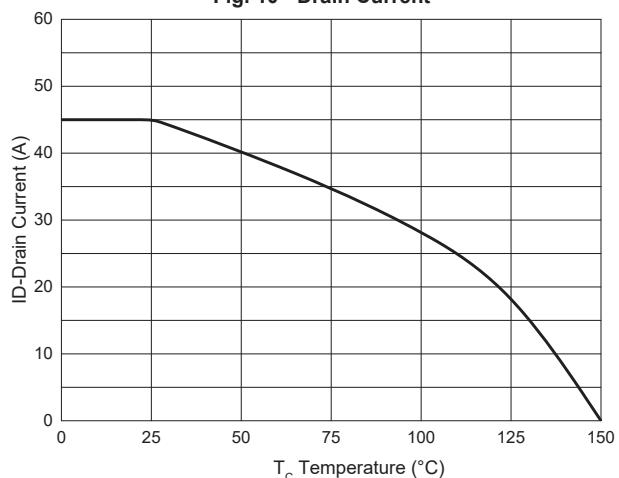
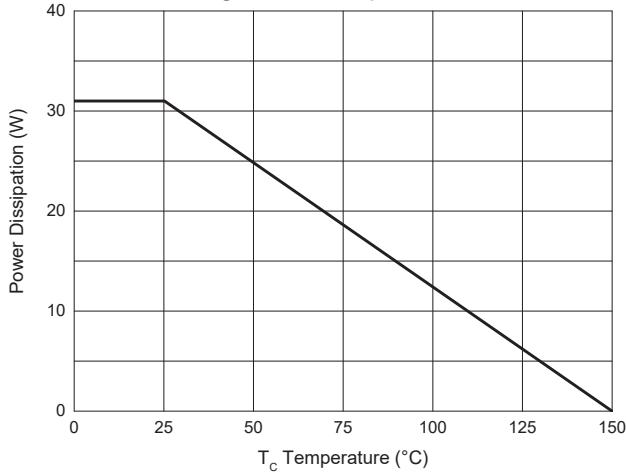


Fig. 11 - PD Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

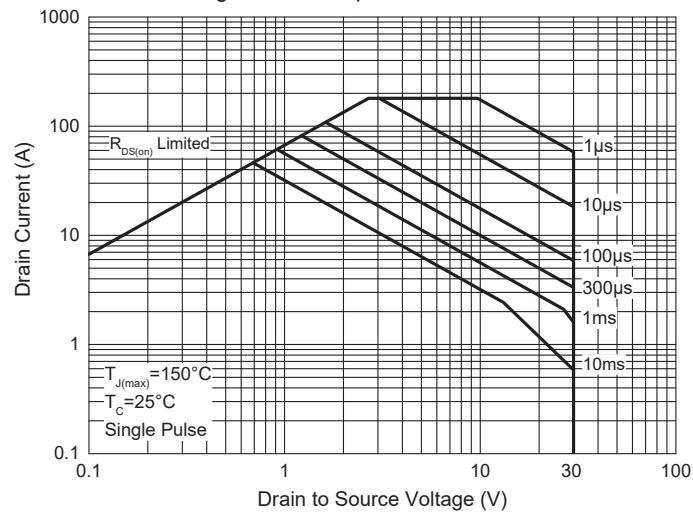
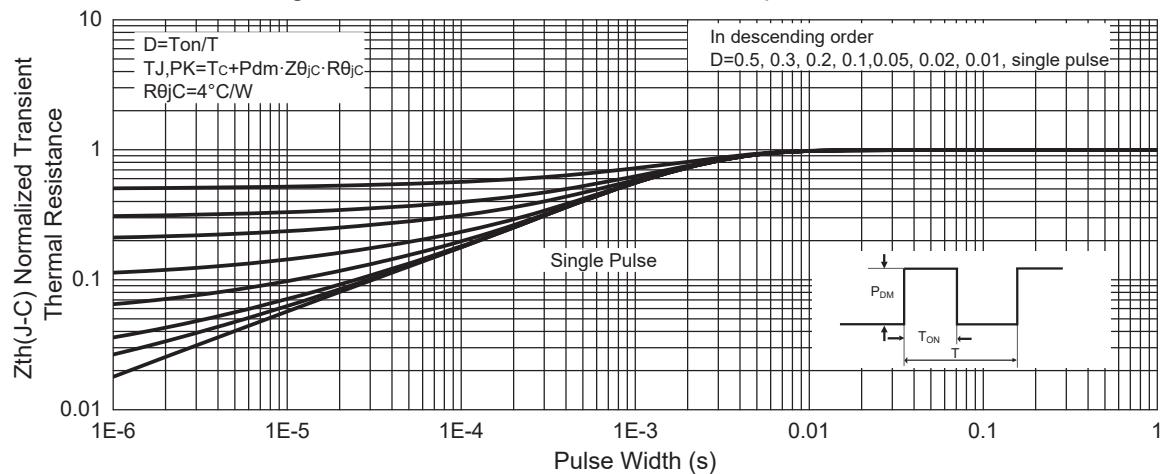


Fig. 13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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